

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IRL2203N, IIRL2203N

• FEATURES

- Static drain-source on-resistance: RDs(on) ≤7.0mΩ
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

· reliable device for use in a wide variety of applications

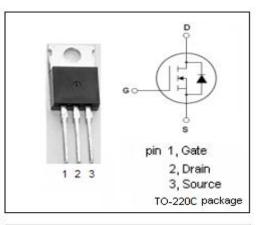
SYMBOL	PARAMETER	VALUE	UNIT			
VDSS	Drain-Source Voltage	30	V			
V _{GS}	Gate-Source Voltage	±16	V			
Ι _D	Drain Current-Continuous	116	А			
I _{DM}	Drain Current-Single Pulsed	400	А			
PD	Total Dissipation @T _c =25°C	180	W			
Tj	Max. Operating Junction Temperature	175	°C			
T _{stg}	Storage Temperature	-55~175	°C			

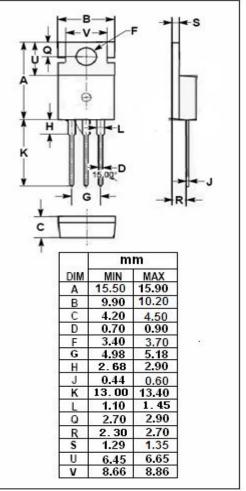
• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.85	°C /W
Rth(ch-a)	ch-a) Channel-to-ambient thermal resistance		°C/W

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isc website: www.iscsemi.cn



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ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID = 250μA	30			v
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =250 μ A	1.0			V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V _{GS} =10V; I _D =60A			7.0	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} =± 16V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =30V; V _{GS} = 0V			25	μA
Vsd	Diode forward voltage	Is =60A, V _{GS} = 0 V			1.2	V

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